NSN 5961-01-307-5349



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-307-5349 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.060 inches and 0.107 inches **End Application:** Countermeasures **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Electrostatic sensitive device **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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